157

A14)

A15)

A16)

A17)

ving:

(B1)

(B2)

(B3)

(B4)

(B5)

VOLUME 157, NUMBER 2

Seo Merill

10 MAY 1967

High-Pressure Study of the First-Order Phase Transition in MnAs

J. B. GOODENOUGH AND J. A. KAFALAS

Lincoln Laboratory,* Massachusetts Institute of Technology, Lexington, Massachusetts

(Received 21 November 1966)

The first-order magnetic-transition temperature in MnAs has been measured as a function of both increasing and decreasing pressure. A critical pressure $P_c \sim 4.6$ kbar has been obtained for the range of stability of the hexagonal phase. The pressure hysteresis increases with decreasing temperatures. Cooling to 77°K under 5 kbar and then releasing pressure gives the B31 phase at atmospheric pressure, and it remains stable on heating to 138°K, where there is an increase of magnetization of over a factor of 50. These data, together with earlier magnetic measurements on the system $MnAs_{1-x}P_x$, demonstrate that the origin of the first-order phase transition is a large exchange striction in the basal planes plus a volume-dependent Weiss molecular field and manganese moment. This volume dependence is due to electron rearrangements associated with a high-spin-to-low-spin transition. The sharpness of the high-spin-to-low-spin transition cannot be accounted for by variations in crystal-field splitting with volume. It is suggested that a bandwidth is increasing with decreasing volume through the maximum bandwidth for spontaneous band ferromagnetism. The critical band appears to consist of t_{\pm} orbitals, which are primarily influenced by the Mn-Mn interactions within basal planes.

I. INTRODUCTION

THE magnetic and structural properties of MnAs L are summarized in Table I. The significant features are: (1) There is a first-order phase change (latent heat 1.79 cal/g) at the ferromagnetic Curie temperature T_c from the hexagonal NiAs (B81) structure at $T < T_c$ to the orthorhombic MnP (B31) structure at $T > T_c$. There is a discontinuous loss of ferromagnetism at T_c , and extrapolation to $T > T_c$ of magnetization versus temperature with a Brillouin function gives an extrapolated Curie temperature for the low-temperature phase $T_c(ext) \approx 127^{\circ}$ C. (2) At a $T_t \approx 127^{\circ}$ C, there is a second-order $B31 \rightleftharpoons B8_1$ transition. There is a maximum in the magnetic susceptibility at T_t , but MnAs is not antiferromagnetic in the interval $T_c < T < T_i$. Rather there is a change in the magnitude of the manganese moment $(d\mu/dT>0)$ in this interval. (3) The high-temperature $(T > T_i)$ hexagonal phase exhibits a Curie-Weiss behavior with a $\mu_{eff} = 4.95 \mu_B$ and a $\theta_f \approx$ 10°C. Since any ferromagnetic temperature is always smaller than θ_f , this implies that the net ferromagnetic coupling in this phase is smaller than that in the lowtemperature $(T < T_c)$ hexagonal phase, which has a $T_{\rm c}({\rm ext}) \approx 127^{\circ}{\rm C}$. (4) A discontinuity of 1.86% in the density at T_c is caused by an expansion in the basal plane below T_c . (5) The B31 structure is derived from the $B8_1$ structure by a displacement of the manganese atoms out of the centers of symmetry of their arsenic interstices to make one shortest manganese-arsenic bond. Alternate [11, 0] rows of manganese are displaced toward one another primarily within the basal planes, and along the hexagonal ch axis metal atoms in alternate basal planes are displaced in opposite directions, as shown in Fig. 1.

Three explanations of the first-order phase change at T_c have been suggested. (1) Kittel¹ developed a thermo-

* Operated with support from the U.S. Air Force.

dynamic theory involving "exchange inversion" to explain the antiferromagnetic \rightleftharpoons ferrimagnetic transition in Mn_{2-x}Cr_xSb and suggested it might be applicable to MnAs. The lack of antiferromagnetic order in the interval $T_c < T < T_t$ rules out this possibility. (2) Bean



FIG. 1. The orthorhombic B31 structure of MnP.

and Rodbell² proposed a thermodynamic theory involving a net ferromagnetic exchange interaction that is sensitive to molar volume, so that

$$T_{c} = T_{0} [1 + \beta (V - V_{0}) / V_{0}].$$
(1)

This motivated DeBlois and Rodbell³ to measure T_c as a function of pressure P and applied field strength Hin the ranges $15 < T < 65^{\circ}$ C, 0 < P < 1 kbar, and 0 < H <110 kOe. They appeared to obtain a qualitative match between theory and experiment. (3) Goodenough⁴ pointed out how the two transitions, $B_1 \rightleftharpoons B31$ at T_c

⁴ J. B. Goodenough, M.I.T. Lincoln Laboratory, Lexington, Massachusetts, Technical Report No. 345, DDC 435758, 1964 (unpublished).

157

(B7)

(B6)

- (B8)

(B9)

¹ C. Kittel, Phys. Rev. 120, 335 (1960).

^{57 389}

² C. P. Bean and D. S. Rodbell, Phys. Rev. **126**, 104 (1962). ³ R. W. DeBlois and D. W. Rodbell, Phys. Rev. **130**, 1347 (1963).

_	the second se			
	Property	$0 < T < T_e$	$T_o < T < T_t$	$T_t < T$
	Magnetic order Molecular moment	Ferromagnetic $\mu_0 = 3.4 \ \mu_B$	Paramagnetic $d\mu/dT > 0$	Paramagnetic $\mu_{off} = 4.95 \ \mu_B$
	Transition temp. (°K) ^b	$T_{e}(\text{ext}) \approx 400;$ $T_{e} \uparrow = 317, T_{e} \downarrow = 307$	$T_{i}\approx400$	$\theta_f = 283$
	Structure $(dV/VdT)_P ({}^{\circ}C^{-1}) \circ$ $c_h/2 (Å)$ $a_h (Å)$ Latent heat (cal/g)	Hexagonal $B8_1$ <0(295°K< $T \le T_e$) >2.85 ≈ 3.72	Orthorhombic B31 $\approx 2 \times 10^{-4}$ ≈ 2.87 3.68-3.70 1.79 at T_e	Hexagonal $B8_1$ $\approx 6 \times 10^{-6}$ ≈ 2.9 > 3.71 None at T_t

TABLE I. Some physical properties of MnAs."

* T. Hirone, Landolt-Börnstein Tabellen (Springer-Verlag, Berlin, 1962), Vol. 6, II/9, pp. 3-14; W. B. Pearson, A Handbook of Lattice Spacings and Structures of Metals and Alloys (Pergamon Press, Inc., New York, 1958), p. 58; R. W. DeBlois and D. S. Rodbell, Phys. Rev. 130, 1347 (1963); J. B. Goodenough, D. H. Ridgley, and W. A. Newman, in Proceedings of the International Conference

on Magnelism, Nottingham, 1964 (The Physical Society and The Institute of Physics, London, 1965), p. 542.

At atmospheric pressure and zero applied field $(\partial T_c/\partial P)_H > 0$; $(\partial T_c/\partial H)_P > 0.$

fixed temperatures between 77 and 300°K. This is con-

• Density increases by 1.86% on heating across T_c .

and $B31 \rightarrow B8_1$ at T_t , could reflect a high-spin manganese configuration in the B81 phase and a low-spin manganese configuration in the B31 phase. This motivated measurements⁵ of the magnetic properties of the systems MnAs1-xPx and MnAs1-ySby, which demonstrated that the B31 phase does contain a much smaller manganese moment (low-spin manganese configuration) and that the range of temperatures over which the high-spin configuration is converted to a low-spin configuration on cooling through T_t is only about 125°C. It was also found that a first-order phase change at T_c only occurs if $T_c > T_t - 125^{\circ}$ C. The addition of phosphorus in the amount of only x > 0.04 is able to stabilize the B31 phase to lowest temperatures.

Since a temperature change is related to a volume change via the thermal expansion coefficient, the experiments on the system $MnAs_{1-x}P_x$ indicate that there is a $d\mu/dV > 0$ for a critical range of volume V corresponding to the 125°C temperature interval below T_t . If this is so, then there should be a critical pressure P_c above which the B31 phase can be stabilized to lowest temperatures. The present study was designed to demonstrate that such a critical pressure exists and to determine its magnitude. Previous pressure studies on MnAs have been confined to P < 2.5 kbar.^{3,6}

Given a critical pressure P_c , the present study also attempts to interpret the significance of the sharpness of the high-spin inat a critical molar volume.

II. EXPERIMENTAL

The pressure dependence of T_c in polycrystalline MnAs was determined by monitoring the change of electrical resistance with hydrostatic pressure at various venient because of a discontinuity in the electrical resistance that occurs at T_c .⁷ The resistance was monitored in the conventional four-probe manner. Two types of apparatus were used: a piston-cylinder apparatus employing isopentane liquid as the transmitting medium and, at the lowest temperatures, a highpressure gas apparatus employing helium gas as the transmitting medium. Constant temperatures were maintained by immersing the pressure vessel in a constant-temperature bath. The room-temperature run shown in Fig. 2 is typical of the data obtained. The transition pressure was chosen as that pressure at which the large change in resistance is initiated. This point has good reproducibility.

Table II gives a summary of the data. In the interval $200 \le T \le 317^{\circ}$ K, the data points for increasing pressure can be fitted by a quadratic equation:

> $P = -5.6230 + 0.1072 T_c - 0.000283 T_c^2$, (2)

where P is the pressure in kbar and T_e is in degrees



FIG. 2. Electrical versus pressure at 25°C of

FIG. 3. T pressure d first-order and $B31 \rightarrow 1$ tions in M 320°K.

⁸ As quotec



390

157

Kelvin at 1 a results Giardir (DeBld $B31 \rightarrow I$ ment w

imply t

done of

single c

see note The r

where t

interval

demonst

which t

tempera

creases

P>2 kb

to stabil fact, it

pheric p from P>

A specin

in the hi

was cool

the speci vibrating

The tr

⁸ J. B. Goodenough, D. H. Ridgley, and W. A. Newman, in Proceedings of the International Conference on Magnetism, Notling-ham, 1964 (The Physical Society and The Institute of Physics, London, 1965), p. 542.

⁶ G. A. Samara and A. A. Giardini, *Physics of Solids at High Pressures* (Academic Press Inc., New York, 1965), p. 308.

TABLE II. Data for the magnetic B81 to B31 transition in MnAs.

Pressure (kbar):	0.001	1.22	2.33	3.73	4.23	4.5	4.5
$B8_1 \rightarrow B31T_e$ (°K):	317	298	278	243	223	201	77
Temperature (°K):	307	298	283	245	240	201	138
$B31 \rightarrow B8_1 P_e$ (kbar):	0.001	0.7	0.9	2.0	1.7	1.4	0.001

Kelvin. Differentiation gives $dT_e/dP = -13.8^{\circ}C/kbar$ at 1 atm. This is in moderate agreement with the results of Rodbell and Wilson⁸ and of Samara and Giardini,6 who report -12 and $-12.3^{\circ}C/kbar$. (DeBlois and Rodbell³ give -24.1°C/kbar for the $B31 \rightarrow B8_1$ transition, which is also in reasonable agreement with Table II and Fig. 3.) However, these authors imply that the slope is constant. Our experiments were done on polycrystalline samples, whereas they used single crystals and were confined to P < 2.5 kbar. (Also see note added in proof at end of paper.)

The pressure dependence of T_e is displayed in Fig. 3, where the smooth curve for increasing pressure in the interval $190 \le T \le 317^{\circ}$ K is Eq. (2). The data clearly demonstrate a critical pressure $P_c \approx 4.6$ kbar above which the B31 phase is indeed stable down to lowest temperatures. In addition, the pressure hysteresis increases with decreasing temperature, so that pressures P>2 kbar applied at room temperature are sufficient to stabilize the B31 phase to lowest temperatures. In fact, it is possible to obtain the B31 phase at atmospheric pressure below 138°K if the pressure is reduced from P > 4.6 kbar at a $T < 138^{\circ}$ K.

The transition at $T = 138^{\circ}$ K was obtained as follows: A specimen of MnAs was placed under 5-kbar pressure in the high-pressure gas apparatus, and the apparatus was cooled to 77°K. Pressure was then released and the specimen transferred to the cold stage $(4.2^{\circ}K)$ of a vibrating-coil magnetometer. At no time was the speci-

320

B31

B8, → B31

33 T.2,

is in degrees

(2)

FIG. 2. Electrical istance versus ssure at 25°C of lycrystalline nAs.

51).



'As quoted by Ref. 3.

120°K.

men allowed to warm up more than a few degrees above 77°K. The magnetic properties were measured from 4.2°K to room temperature. Below 138°K there was a small susceptibility that decreased with increasing temperature. An abrupt transition occurred at 138°K. the magnetization increasing by over a factor of 50 to the magnetization value of the $B8_1$ phase.

Although the low-temperature B31 phase appeared to resemble the metamagnetic phase of low-temperature MnP and MnAs_{0.9}P_{0.1}, our preliminary measurements on a polycrystalline sample do not allow characterization of the magnetism of this phase. This point is significant because Rodbell and Bean⁹ have anticipated a ferromagnetic → antiferromagnetic phase change with increasing pressure at low temperatures. A pressure bomb for further magnetic studies is under construction. Meanwhile, monitoring of the resistance at room temperature up to 12 kbar has shown only one first-order phase change. The Rodbell-Bean P^* -T phase diagram contains $P^* = P - \alpha_l T/K$, where α_l is the thermal expansion coefficient and K is the compressibility. Their diagram would reflect the P^* -T curve through the $P^* = [4.6 + (\alpha_l T/K)]$ kbar line to predict a roomtemperature paramagnetic
→ antiferromagnetic phase change near $[8+(\alpha_l T/K)]$ kbar=11.8 kbar. If such a transition exists below 12 kbar, it is not first-order. Further, reduction in temperature under P=3 kbar from the paramagnetic B31 phase at room temperature and 3 kbar gave no anomaly in the resistance down to 90°K. Since the high-pressure phase is magnetically ordered at 90°K, this means that the paramagnetic ₹ magnetic-order transition in the high-pressure phase is not first-order. (The magnetic-order transition temperature for the high-pressure phase is not indicated in Fig. 3 since it is not clearly defined by a resistivity anomaly.) Therefore, it may be assumed that the highpressure phase retains the B31 structure in the areas so designated in Fig. 3 and that there is no crystallographic phase change associated with magnetic ordering in the high-pressure phase.

III. DISCUSSION

A. Significant Observations

These results, together with the earlier study⁵ of $MnAs_{1-x}P_x$ and the data of Table I, establish the

157

The Institute of

 $(\partial T_e/\partial P)_H > 0;$

This is con-

ie electrical

e was moni-

anner. Two

cylinder ap-

transmitting

res, a high-

1 gas as the

atures were

ssel in a con-

peraty run

btaine... The

sure at which

d. This point

n the interval

asing pressure

157

391

⁹ D. S. Rodbell and C. P. Bean, J. Appl. Phys. Suppl. 33, 1037 (1962).

following facts that are important for any theory of the transitions at T_c and T_t in MnAs:

1. There is a $d\mu/dV > 0$ in the temperature interval $T_t - \Delta T < T < T_t$, where $\Delta T \approx 125^{\circ}$ C.

2. From Table I, the thermal expansion coefficient in this temperature interval is about 2×10^{-4} °C⁻¹, so that $d\mu/dV > 0$ occurs in a critical molar volume range $V_t - \Delta V < V < V_t$, where V_t is the molar volume at T_t and

$$\Delta V/V \approx 0.025. \tag{3}$$

3. A first-order $B8_1 \rightleftharpoons B31$ transition at T_c only occurs if the molar volume at T_c falls within the critical range $V_t - \Delta V < V < V_t$. Further, the fact that the lowtemperature phase is hexagonal, with a discontinuous expansion of the basal planes on cooling through T_c , demonstrates that there is a large, positive exchange striction in the basal planes if $V > V_t - \Delta V$ at T_c . This exchange striction has essentially disappeared where $V < V_t - \Delta V$.

B. Contact with Thermodynamic Theory

Since the Curie temperature is proportional to $W\mu^{*2}$, where $\mu^{*2} \approx 4S(S+1)\mu_B^2$ and W is the ferromagnetic Weiss molecular field, it follows from Eq. (1) that

$$\beta = V \left(W^{-1} \frac{dW}{dV} + \frac{2}{\mu^*} \frac{d\mu^*}{dV} \right). \tag{4}$$

Bean and Rodbell² have shown that if this parameter is large enough, then the change in volume associated with the large exchange striction can produce a firstorder phase change at T_c . Bean and Rodbell assumed $d\mu^*/dV=0$ and therefore that there is a large dW/dV>0. The fact that $d\mu^*/dV\neq 0$ means that this assumption must be modified.

The B31 phase of MnAs_{0.96}P_{0.04} has a $T_c \equiv T_{31} \approx 230^{\circ}$ K and the hexagonal B8₁ phase of MnAs has a $T_c(\text{ext}) \equiv T_8 \approx 400^{\circ}$ K. Since the Curie temperature is proportional to $W\mu^{*2}$, this gives

$$\frac{T_8 - T_{31}}{T_8} = \frac{W_8 - (\mu_{31}^* / \mu_8^*)^2 W_{31}}{W_8} \approx \frac{170}{400}.$$
 (5)

It follows that dW/dV < 0, if $(\mu_8^*/\mu_{31}^*)^2 > 40/23$, and

$$\beta \approx (V/\Delta V) \left[1 - (\mu_8^*/\mu_{31}^*)^2 (23/40) + 2 - 2(\mu_{31}^*/\mu_8^*) \right] \\\approx 50 \left[3 - 0.575 (\mu_8^*/\mu_{31}^*)^2 - 2(\mu_{31}^*/\mu_8^*) \right], \tag{6}$$

Hence

$$\beta > 6$$
 if $(\mu_8^*/\mu_{31}^*)^2 \le 3.$ (7)

Here $\Delta V/V \approx 0.02$ is taken from the discontinuous volume change at T_c , and a $\beta > 6$ could be large enough to account for the first-order phase change.³ Although this places an upper limit on the change in μ^* at T_c , it is shown below that this limit is compatible with the changes that are observed.

C. Atomic Theory

Thus far we have seen that the first-order transition at T_e in MnAs can be accounted for by a volumedependent atomic moment and Weiss molecular field within a critical range of volumes $V_t - \Delta V < V < V_t$. We must now inquire into the atomic mechanisms responsible for such a volume dependence within a small volume interval about a critical molar volume.

1. Origin of $d\mu/dV > 0$

The electronegativity difference between manganese and arsenic is sufficiently large that there is an energy gap between the bonding and antibonding s and porbitals. It is reasonable to assume that, as in the semiconductor GaAs, the Fermi energy lies in the gap, so that the bonding orbitals form a filled valence band and the antibonding orbitals form an empty conduction band. This leaves four electrons per molecule to be placed in the manganese 3d orbitals.

Schematic one-electron energies for the 3d orbitals are shown in Fig. 4. The cubic component of the crystalline fields at an octahedral-site manganese atom splits the orbitally fivefold-degenerate 3d level in two: a less stable level for the two e_q orbitals directed toward the anions and a more stable level for the remaining three t_{2q} orbitals. The t_{2q} level is split by the positive trigonal component of the field into a more stable level for the t_0 orbital directed along the hexagonal c_h axis and a less stable level for two t_{\pm} orbitals primarily directed within basal planes. In addition, covalent mixing between manganese e_q orbitals and arsenic s and p orbitals is large enough to make the e_q orbitals collective, band



FIG. 4. Schematic one-electron energies for 3d electrons in MnAs, given localized t_{\pm} electrons: (a) high-spin manganese $(\epsilon_{ex} > \epsilon_{of})$ and (b) low-spin manganese $(\epsilon_{of} > \epsilon_{ex} + \epsilon_s)$. Splittings of i_{\pm} and e_g bands of low-spin phase is due to orthorhombic symmetry of B31 structure.

towar in low Fig and **a**

The m mome tion o Fron tion fo

Since a terval,

¹⁰ J. B presente liques, U ¹¹ J. B Wiley & ¹² C. G lished)] $n \approx 0.3$, t either va

392

157

orl ba set

bai

tio

15

in

tior fille

nar

of t

Thi

ator

elec

orbi

split

crys

band

of tl

sepa

 e_q or

with

gives

 $-\epsilon_{s}<$

in Fi

per a

mang

where

Fi

1

transi

volume-

ular field $< V < V_t$

nisms ren a small

langanese

an energy

s and p

as in the

1 the gap,

ence band

onduction

ule to be

d orbitals

he crystal-

tom splits

wo: a less

oward the

ning three

ve trigonal

vel for the

and a loss

ted w 1

g between

orbitals is

tive, band

EF

EF

he.

157

FIRST-ORDER PHASE TRANSITION IN MnAs

orbitals,¹⁰ so their energies are distributed over a narrow bandwidth. Similarly the short (<2.9 Å) Mn-Mn separation along c_h means the t_0 orbitals are collective, band orbitals.¹¹ The larger (≈ 3.7 Å) Mn-Mn separations within basal planes, on the other hand, are compatible with t_{\pm} orbitals that are either localized or, if collective, very narrow-band. These are shown as localized orbitals in Fig. 4, as narrow-band orbitals in Fig. 5.

The fact that low-temperature MnAs has a saturation moment of $\mu_0 = 3.1 \mu_B^3$ indicates that the partially filled l_{\pm} orbitals are either localized or sufficiently narrow-band to support a spontaneous magnetization of the bonding as well as the antibonding orbitals.12 This spontaneous magnetization creates an intraatomic-exchange interaction with the other d-band electrons so as to lift the spin degeneracy of all the dorbitals. We shall define ϵ_{ex} as the intra-atomic-exchange splitting of the bottom of the d bands and ϵ_{of} as the crystal-field splitting from the bottom of the α -spin t_0 band to the density-of-states minimum near the middle of the α -spin e_{α} bands. (A density-of-states minimum separates cation-sublattice bonding versus antibonding e_q orbitals, even though all e_q orbitals are antibonding with respect to the anion sublattice.)

Figures 4(a) and 5(a) correspond to $\epsilon_{ex} > \epsilon_{of}$, which gives a high-spin manganese moment $\mu_8 = 4\mu_B$. If $-\epsilon_s < (\epsilon_{ex} - \epsilon_{ef}) < 0$, where $\epsilon_s = \epsilon_1 + \epsilon_2$ is the energy shown in Fig. 4(b) or 5(b), then there are 0 < n < 1 electrons per atom in the β -spin t_0 orbitals, and the high-spin manganese atomic moment is somewhat reduced to

$$\mu_8 = (4 - 2n) \mu_B, \tag{8}$$

where *n* increases towards n=1 as $(\epsilon_{ex}-\epsilon_{of})$ decreases towards $-\epsilon_s$. A $\mu_0 = 3.1 \mu_B$ would correspond to $n \approx 0.45$ in low-temperature MnAs.

Figures 4(b) and 5(b) correspond to $(\epsilon_{ex} - \epsilon_{of}) < -\epsilon_{s}$ and a low-spin atomic moment μ_{31} , where

$$1\mu_B < \mu_{a1} < 2\mu_B.$$
 (9)

The maximum spin-only moment is $2\mu_B$. The minimum moment of $1\mu_B$ corresponds to a spontaneous magnetization of only antibonding l_{20} electrons.

From these considerations, it follows that the condition for a $d\mu/dV > 0$ is

$$-\epsilon_s < (\epsilon_{\rm ex} - \epsilon_{\rm of}) \le 0, \qquad d(\epsilon_{\rm ex} - \epsilon_{\rm of})/dV > 0.$$
 (10)

Since a $d\mu/dV > 0$ is restricted to a critical volume interval, this requires that over this interval

$$\Delta(\epsilon_{\rm ex} - \epsilon_{\rm of}) \geq \epsilon_s, \tag{11}$$

¹⁰ J. B. Goodenough, J. Appl. Phys. 37, 1415 (1966); and speech presented at Colloque International sur les Dérives Semimétal-liques, University of Paris, 1965 (unpublished). ¹¹ J. B. Goodenough, *Magnetism and the Chemical Bond* (John Wiley & Sons, Inc., New York, 1963). ¹² C. Guillaud [thesis, University of Strasbourg, 1943 (unpub-lished)] reports $\mu_0=3.4 \ \mu_B$. This would change *n* of Eq. (8) to $n\approx0.3$, but does not alter the argument that follows because for either value $0 \le n \le 0.5$ either value 0 < n < 0.5.



FIG. 5. Schematic one-electron energies for 3d electrons in MnAs, given collective t_{\pm} electrons: (a) high-spin manganese $(\epsilon_{ex} > \epsilon_{of}$ and $\Delta_b t < \Delta_o t)$ and (b) low-spin manganese $(\Delta^t_{ob} < \Delta_c t < \Delta_b t)$. Splittings of bands of low-spin phase is due to orthorhombic symmetry of B31 structures.

where an $\epsilon_s \ge 0.1$ eV can be anticipated. Now ϵ_{of} is proportional to $V^{-1/3}$, so that

$$\Delta(-\epsilon_{\rm of}) \approx \frac{1}{3} \epsilon_{\rm of} \Delta V / V \approx 0.01 \text{ eV}, \tag{12}$$

where $\Delta V/V \approx 0.025$ from Eq. (3) and $\epsilon_{ef} \approx 1-2$ eV is known from spectroscopic data. The fact that $\Delta(-\epsilon_{\rm of}) < kT$ in the critical temperature interval shows that the low-spin in transition cannot be due $d(-\epsilon_{\rm of})/dV$ alone, and we are forced to assume that

$$\Delta \epsilon_{\rm ex} = \langle d\epsilon_{\rm ex}/dV \rangle \Delta V \geq 0.1 \text{ eV}$$
(13)

within the small, critical volume interval. This, in turn, implies that there is a critical molar volume, and hence a critical bandwidth for the t_{\pm} electrons, at which there is a sharp change in the magnitude of the intraatomic-exchange splitting responsible for a spontaneous atomic moment.

Note that with $\mu_8 = 3.1 \mu_B$, $\mu_8^{*2} \approx 17 \mu_B^2$. Therefore Eq. (7) requires $\mu_{31}^{*2} \ge 5.3 \mu_B^2$, which from Eq. (9) is satisfied so long as μ_{31}^* refers to the intermediate state of Eq. (10).

2. Origin of a Sharp Change in ϵ_{ex} with Bandwidth

Spontaneous atomic moments may occur if the delectrons are localized. Measurements13 on LaCoO3 appear to have demonstrated that, in this compound at least, a localized-electron and a collective-electron state correspond to two thermodynamically different electronic phases and that there is a first-order phase change from one to the other at some critical overlap integral Δ_{e} . In a tight-binding approximation, the

13 P. M. Raccah and J. B. Goodenough, Phys. Rev. 155, 932 (1967).

393

electrons in n manganese Splittings of 4 bic symmetry



FIG. 6. Schematic representation of the meaning of the critical overlap integrals Δ_c and Δ_c^{f} .

bandwidth is proportional to a transfer integral, which is in turn proportional to an overlap integral Δ . Figure 6 shows schematically the localized-electron and collective-electron domains separated by a sharply defined Δ_{c} , corresponding to a critical bandwidth.

Stoner¹⁴ has pointed out that there is a maximum bandwidth, corresponding to a Δ_c^f , that will support spontaneous band ferromagnetism. Therefore Fig. 6 also separates schematically the domain of spontaneous band ferromagnetism from the domain of band paramagnetism.

Finally, it is also known that bonding orbitals have a greater bandwidth than the corresponding antibonding orbitals, or $\Delta_b > \Delta_{ab}$. This distinction is meaningful in the present context, since the t_{2g} orbitals may be bonding or antibonding with respect to Mn-Mn interactions even though they are only antibonding with respect to the arsenic array. Since $\Delta_c \leq \Delta_c^{I}$, the conditions for spontaneous ferromagnetism in MnAs include

$$\Delta_b{}^t < \Delta_c{}^f, \tag{14}$$

$$\Delta_{ab}{}^t < \Delta_c{}^f < \Delta_b{}^t. \tag{15}$$

Equation (14) must be satisfied if the atomic moments are high-spin µ8, since this requires spontaneous magnetization of bonding as well as antibonding orbitals. Either Eqs. (14) or (15) may be satisfied if the atomic moments are low-spin μ_{31} . However, if Eq. (15) applies, then ϵ_{ex} does not resolve the α -spin and β -spin t_{2g} energies, and the manganese atoms are necessarily low-spin $(\mu \approx 1\mu_B)$, as shown in Fig. 5(b). In this case, three of the four d electrons are spin-paired in bonding t_{2q} orbitals and only the remaining antibonding electron is spontaneously magnetized. Thus a sharp $d\epsilon_{ex}/dV > 0$ at a critical volume implies

$$\Delta_b{}^t < \Delta_c{}^f \to \Delta_{ab}{}^t < \Delta_c{}^f < \Delta_b{}^t. \tag{16}$$

3. Origin of the Exchange Striction and dW/dV

The sign of the magnetic coupling depends upon the occupancy of the orbitals11,15: (a) Half-filled localized-

electron orbitals couple antiferromagnetically and halffilled bands would stabilize an antiferromagnetic spindensity wave rather than spontaneous ferromagnetism. (b) Orbitals more than half-filled, localized or collective, may exhibit spontaneous ferromagnetism. (c) Localized electrons coupled via conduction electrons in a band less than one-quarter filled exhibit ferromagnetism.

With these rules for the signs of the magnetic couplings, we now inquire about the nature of the magnetic couplings within the three phases of MnAs.

(a) Low-temperature B81 phase. According to our analysis and the reduced moment $\mu_8 = (4-2n)\mu_B =$ $3.1\mu_B$, this phase has

$$-\epsilon_s < (\epsilon_{\rm ex} - \epsilon_{\rm of}) < 0,$$
 (17)

and $n \approx 0.45 \beta$ -spin t_0 electrons per atom. This means that the to orbitals are more than half-filled and so support ferromagnetic coupling. (Note that so long as n < 0.5, only bonding β -spin orbitals are occupied.) The t_{\pm} orbitals, on the other hand, are only half-filled. Therefore forced ferromagnetic coupling reduces the Mn-Mn bonding in the basal planes, thus introducing a large, positive exchange striction below T_c . It simultaneously localizes the α -spin t_{\pm} electrons, since the α -spin t_{+} orbitals, bonding and antibonding, are completely filled. (If both bonding and antibonding orbitals are filled, localized and band descriptions become equivalent.¹⁶) The ferromagnetic coupling can be forced by the coupling via collective e_q electrons. However, the Weiss molecular field W_8 contains a negative contribution from the Mn-Mn interactions in basal planes, which tends to reduce it.

(b) The B31 phase. A low-temperature, high-pressure B31 phase has low-spin manganese and

$$(\epsilon_{ex} - \epsilon_{of}) < -\epsilon_s,$$
 (18)

corresponding to Figs. 4(b) and 5(b). The e_g bands are empty and the t_{2q} bands are two-thirds filled. Therefore all the Mn-Mn interactions are potentially ferromagnetic and spontaneous ferromagnetism occurs as long as $\Delta_{ab}{}^t < \Delta_c{}^f$. This means there is no anomalous exchange striction at T_c and no negative component in the Weiss molecular field W_{31} . This is consistent with Eq. (5), or

$$V_{31} = (\mu_8^* / \mu_{31}^*)^2 \frac{23}{40} W_8 > W_8.$$
(19)

At intermediate temperatures, where Eq. (17) applies, the electron distribution amongst the d bands is changing rapidly with temperature, so that $d\mu/dV > 0$ and dW/dV < 0, the Weiss molecular-field constant W decreasing as the β -spin t electrons disappear because with zero β -spin t electrons the Mn-Mn interactions become antiferromagnetic.

(c) High-temperature B81 phase. The model suggests that for $T > T_t$

$$\epsilon_{\rm ex} - \epsilon_{\rm of} > 0. \tag{20}$$

¹⁶ F. Seitz, *The Modern Theory of Solids* (McGraw-Hill Book Company, Inc., New York, 1940), p. 301.

In thi via cc

these

intera

the ne smalle β -spin sisten than (20)for Tto S=(a) rhoml not re

bilizes

orbita

the t

force

elsewł

(b)

394

or

157

157

the M all rep excha 1. the Bperati molar transi a criti is a c atomi 2. ' repres taneo orbita volum

sharp

3.

crysta

mang

intern

symm

hexag

stricti

17 T.

Structu

(unpul

 ¹⁴ E. C. Stoner, Phil. Mag. 25, 899 (1938).
 ¹⁵ J. B. Goodenough, J. Appl. Phys. 38, 1054 (1967).

157

157

d halfc spin netism collecn. (c) ectrons ferro-

agnetic of the nAs. to our $n)\mu_B =$

(17)

means and so so long upied.) f-filled. ces the oducing simulnce the re comorbitals become can be s. Ho regative n basal

pressure

(18)

ands are herefore rromagas long xchange he Weiss . (5), or (19)

(17) apbands is $\mu/dV > 0$ stant W because eractions

suggests

(20) -Hill Book In this configuration only the Mn-As-Mn interactions via collective e_q electrons are ferromagnetic. Although these may dominate the antiferromagnetic Mn-Mn interactions within basal planes and along the c_h axis, the net ferromagnetic Weiss molecular field W must be smaller than in the low-temperature $B8_1$ phase, where β -spin t_0 electrons are present. This conclusion is consistent with a high-temperature $\theta_f = 283^{\circ}$ K being smaller than the low-temperature $T_c(\text{ext}) \approx 400^{\circ}$ K. Equation (20) is also consistent with the molar Curie constant for $T > T_t$, which gives a $\mu_{\text{eff}} = 4.95\mu_B$, corresponding to S=2.

4. Comments on Symmetry Changes

(a) The distortion from hexagonal $B8_1$ to orthorhombic B31 symmetry is in such a direction that it does not remove the t_{\pm} orbital degeneracy, but rather stabilizes the bonding orbitals relative to the antibonding orbitals. Thus the distortion is in a direction that favors the transition of Eq. (16). (However, the driving force for the B31 distortion below T_t probably lies elsewhere.^{10,17})

(b) The low-temperature phase is hexagonal because the Mn-Mn interactions within the basal planes are all repulsive below T_c , giving rise to the large, positive exchange striction.

IV. CONCLUSIONS

1. The existence of a critical pressure above which the B31 phase is stabilized shows that the critical temperature interval in $MnAs_{1-x}P_x$ is related to a critical molar volume. Since there is a high-spin \rightleftharpoons low-spin transition within this critical molar volume, this implies a critical bandwidth, or overlap integral, at which there is a dramatic change in the magnitude of the intraatomic-exchange energy.

2. The critical bandwidth, or overlap integral Δ_c^f , represents the maximum value that can support spontaneous magnetization of collective electrons in bonding orbitals. Therefore the sharpness of the region of molar volumes over which $d\epsilon_{ex}/dV > 0$ indicates that Δ_d^f has a sharp empirical definition.

3. Where high-spin manganese are present, the crystal symmetry is hexagonal $B8_1$; where low-spin manganese are present, it is orthorhombic B31. In the intermediate state, corresponding to Eq. (17), the symmetry is orthorhombic if $T > T_c$, but becomes hexagonal if $T < T_c$ because of a large, positive exchange striction in the basal planes. This exchange striction

¹⁷ J. B. Goodenough, speech presented at the Symposium on Structural Inorganic Chemistry in Halifax, Nova Scotia, 1965 (unpublished). arises from half-filled t_{\pm} orbitals, which produce antiferromagnetic Mn-Mn interactions within a basal plane. There is no exchange striction along c_h , because β -spin t_0 electrons are present to make the Mn-Mn interactions in this direction ferromagnetic.

4. The magnitude of the atomic moment $\mu_0 = 3.1\mu_B$, of a paramagnetic Curie temperature $\theta_f < T_c(\text{ext})$, of a Weiss molecular field $W_{31} > W_8$, corresponding to dW/dV < 0, of an effective paramagnetic moment $\mu_{\text{eff}} = 4.95\mu_B$, corresponding to S=2, and of $d\mu/dV > 0$ are all consistent with a model in which Eq. (10) applies within the small volume interval about a critical molar volume.

5. On a macroscopic, thermodynamic scale, a firstorder transition at T_e occurs because of the coincidence of a large exchange striction with a volume-dependent Weiss molecular field W and manganese moment μ . The Curie temperature may be expressed by Eq. (1), where the significant parameter is $\beta \sim 10$. Further, since the free energy of the ferromagnetic phase contains a magnetic term, T_e increases with applied magnetic field.

In addition, the l_{\pm} electrons appear to be localized in the ferromagnetic B81 phase and collective in the B31 phase. Since experiments¹³ on LaCoO₃ have shown first-order a transition, it is possible that an electronic latent heat may also contribute to the first-order transition in MnAs. Note added in proof: N. P. Grazhdankina and Yu. S. Bersenev [Zh. Eksperim. i Teor. Fiz. 51, 1052 (1966) report changes with temperature in the resistivity and magnetic state of MnAs at different pressures that are in reasonable agreement with our results above 230°K. They report a $dT_c/dP = -(16.0\pm0.3) \text{ deg/kbar}$ with increasing temperature and a $dT_e/dP = -(34\pm7)$ deg/kbar with decreasing temperature. They also found a second-order magnetic transition in the high-pressure phase having $T_N \approx 230^{\circ}$ K at 3 kbar, as obtained indirectly by us from the $MnAs_{1-x}P_x$ system, and a $dT_N/dP = (2.22 \pm 0.07) \ 10^{-3} \ deg/kbar$. They also present magnetic data that indicate the presence, in their experiments, of mixed B81 and B31 phases after cooling through the magnetic transition in the hysteretic region of the P-T diagram.

ACKNOWLEDGMENTS

We would like to thank W. A. Newman for supplying the samples of stoichiometric (wet analysis and x-rays) MnAs and for his enthusiastic interest in this study. We would also like to thank N. Menyuk and K. Dwight for monitoring the magnetization-versus-temperature study cited.